XP01401 (XP1401)

Silicon PNP epitaxial planar type

For general amplification

Features

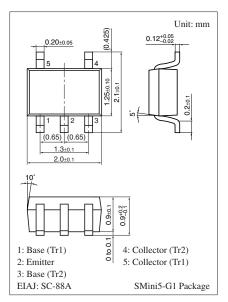
- Two elements incorporated into one package (Emitter-coupled transistors)
- Reduction of the mounting area and assembly cost by one half

Basic Part Number

• 2SB0709A (2SB709A) × 2

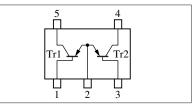
Symbol	Rating	Unit						
V _{CBO}	-60	V						
V _{CEO}	-50	V						
V _{EBO}	-7	V						
I _C	-100	mA						
I _{CP}	-200	mA						
P _T	150	mW						
Tj	150	°C						
T _{stg}	-55 to +150	°C						
	Symbol V _{CBO} V _{CEO} V _{EBO} I _C P _T T _j	$\begin{tabular}{ c c c c } \hline Symbol & Rating \\ \hline V_{CBO} & -60 \\ \hline V_{CEO} & -50 \\ \hline V_{EBO} & -7 \\ \hline I_C & -100 \\ \hline I_{CP} & -200 \\ \hline P_T & 150 \\ \hline T_j & 150 \\ \hline \end{tabular}$						

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol: 5V

Internal Connection

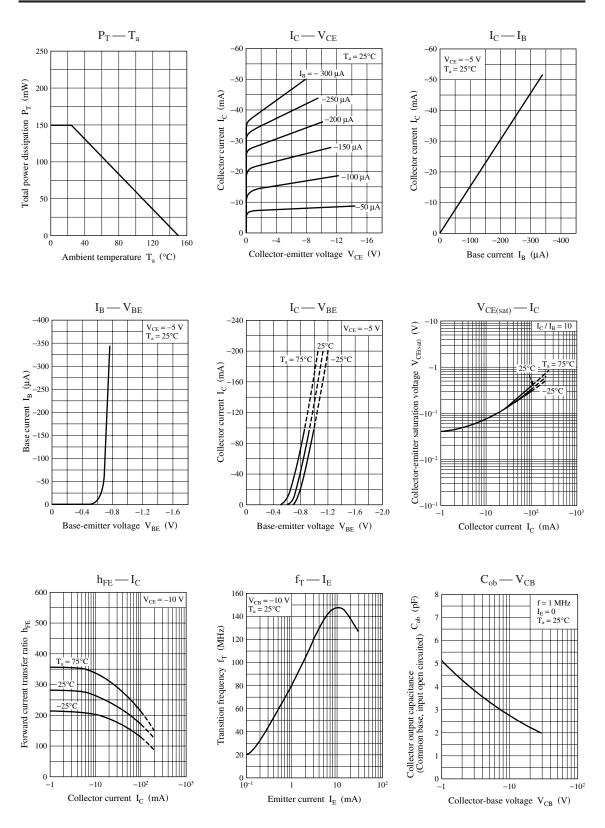


Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu A, \ I_{\rm E} = 0$	-60			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -2 {\rm mA}, I_{\rm B} = 0$	-50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_E = -10 \ \mu A, \ I_C = 0$	-7			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = -10 V, I_B = 0$			-100	μΑ
Forward current transfer ratio	h _{FE}	$V_{CE} = -10 \text{ V}, I_C = -2 \text{ mA}$	160		460	—
h _{FE} ratio *	h _{FE(Small/}	$V_{CE} = -10 \text{ V}, I_C = -2 \text{ mA}$	0.50	0.99		_
	Large)					
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{C} = -100 \text{ mA}, I_{B} = -10 \text{ mA}$		- 0.3	- 0.5	V
Transition frequency	f _T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		2.7		pF
(Common base, input open circuited)						

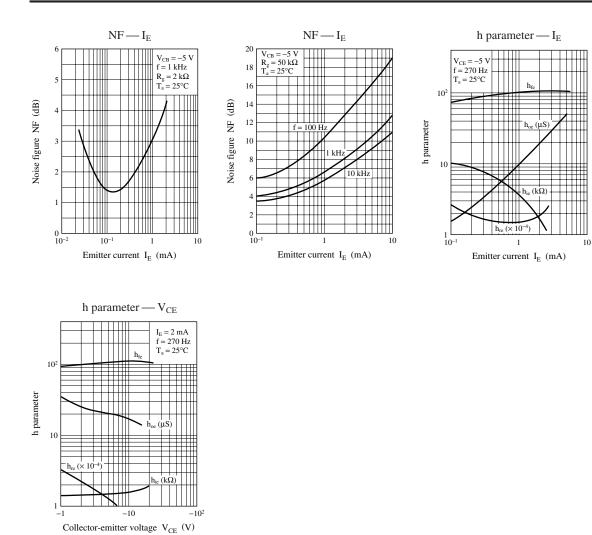
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Ratio between 2 elements

Note) The part number in the parenthesis shows conventional part number.



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